

Amendments to the Specification:

At Page 1, line 1, is to be deleted.

At Page 1, line 4, a new paragraph entitled "Cross Reference to Related Application" is to be added, just below the Title, as follows:

The present application is a continuation of US Application Serial No. 10/129,502 filed on May 6, 2002, ^{now Patent 6,716,666} which is a 371 of PCT/AU02/00008 filed on January 8, 2002, all of which are herein incorporated by reference.

The Paragraph beginning at Page 6, lines 2-10, is to be amended as follows:

An array of caps 48 is formed using conventional injection molding methods and steel mold tools 50 & 52. The caps are supported on a sprule 54 at the same nominal spacing as the groups 42. Using this method will almost invariably lead to misalignment with resulting destruction of MEMS devices, as shown in figure 20. In figure 20 ~~7~~ the cap 48a has been aligned correctly with its group of MEMS devices 42a. However the spacing between the caps is greater than the spacing of the groups so that cap 48b is not aligned correctly, but does not destroy any of the MEMS devices of its respective group 42b. However, the caps 44c & d 48d are sufficiently misaligned that the perimeter walls of the caps overlay one or more of the MEMS devices 44, destroying their functionality.

The Paragraph beginning at Page 8, lines 20-29, is to be amended as follows:

The sheet 134 may be heated by conduction but is preferably heated by radiation and preferably by using infrared (IR) radiation, as indicated by arrows 136 in figure 12. A combination of conductive and radiant heating may be used. The mold and release wafers 102 & 104 and 118 & 120 respectively are formed of silicon, which is substantially transparent to infrared light of a wavelength in the range of about 1000 nm to about 5000 nm. The material 134 chosen either intrinsically absorbs light within this wavelength range or is doped so as to absorb light within this wavelength range. If the material 134 does not intrinsically absorb within this range, a suitable dopant is "carbon black" (amorphous carbon particles) which absorbs light at these wavelengths. Other suitable dopants may be used.